General purpose amplification (–30V, –5A) **QST3**

Application

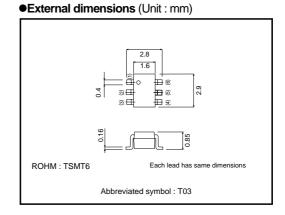
Low frequency amplifier Driver

Features

1) Collector current is large.

2) Collector saturation voltage is low. $V_{CE(sat)} \leq -250 mV$

At Ic = $-2A/I_B = -40mA$



Equivalent circuit

1pin 2pin

5pin

4pin

3pin

6pin

●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol Limits		Unit	
Collector-base voltage	Vсво	-30	V	
Collector-emitter voltage	VCEO	-30	V	
Emitter-base voltage	Vebo	-6	V	
Collector current	lc	-5	А	
Collector current	Іср	-8	A *1	
Dewer dissipation	Pc	500	mW *2	
Power dissipation	PC	1.25	W *3	
Junction temperature	Tj	150	°C	
Range of storage temperature	Tstg	-55 to +150	°C	

*1 Single pulse, Pw=1ms

*2 Each Terminal Mounted on a Recommended *3 Mounted on a 25mm×25mm×¹0.8mm Ceramic substrate

•Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	ВУсво	-30	-	-	V	Ic=-10μA
Collector-emitter breakdown voltage	BVCEO	-30	-	-	V	Ic=-1mA
Emitter-base breakdown voltage	ВVево	-6	-	-	V	I _E =-10μA
Collector cutoff current	Ісво	-	-	-100	nA	Vcb=-30V
Emitter cutoff current	Іево	-	-	-100	nA	Veb=-6V
Collector-emitter saturation voltage	VCE(sat)	-	-170	-250	mV	Ic=-2A, IB=-40mA
DC current gain	hfe	270	-	680	-	Vce=-2V, Ic=-500mA *
Transition frequency	fт	-	200	-	MHz	Vce=-2V, Ie=500mA, f=100MHz *
Corrector output capacitance	Cob	-	60	_	pF	Vcb=-10V, Ie=0A, f=1MHz

ROHM

*Pulsed

Rev.B

Transistors

Packaging specifications

	Package	Taping	
Туре	Code	TR	
	Basic ordering unit (pieces)	3000	
QST3		0	

•Electrical characteristic curves BASE SATURATION VOLTAGE : Vec (sai) (V) COLLECTOR SATURATION VOLTAGE : Vcc (sai) (V) COLLECTOR SATURATION VOLTAGE : Vcc (sai) (V) 1000 COLLECTOR SATURATION VOLTAGE : VCE(sat) (V) lc/lв=50/1 Pulsed Ic/Is=20/ Pulse ++ hFE =50/ DC CURRENT GAIN: =20/ 0. а= –4 Га=12 10 0.0 VCE=2V Pulsed 10 **1**0.00 0.01 0.1 0.01 0.1 COLLECTOR CURRENT : Ic (A) COLLECTOR CURRENT : Ic (A) COLLECTOR CURRENT : Ic (A) Fig.2 Collector-emitter saturation voltage Fig.1 DC current gain Fig.3 Collector-emitter saturation voltage base-emitter saturation voltage vs. collector current vs. collector current vs. collector current 1000 EMITTER INPUT CAPACITANCE : Cib (pF) COLLECTOR OUTPUT CAPACITANCE : Cob (pF) VCE=2 Ta=25°C Ic=0A f=1MHz TRANSITION FREQUENCY : $f_{\rm T}$ (MHz) lc/Iв=20/ VCE=-2V Pul COLLECTOR CURRENT : Ic (A) Pulsed f=100MH Ta=25° Cib 100 100 Cob # 0.001 10 L 0.01 0.1 BASE TO EMITTER CURRENT : VBE (V) EMITTER TO BASE VOLTAGE : V_{EB} (V) COLLECTOR TO BASE VOLTAGE : V_{CB} (V) EMITTER CURRENT : IE (A) Fig.4 Grounded emitter propagation Fig.5 Gain bandwidth product Fig.6 Collector output capacitance characteristics vs. emitter current vs. collector-base voltage Emitter input capacitance

vs. emitter-base voltage

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